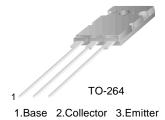


KSA1943

Audio Power Amplifier

- High Current Capability I_C = -13A
- High Power Dissipation
- · Wide S.O.A
- Complement to KSC5200



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	-230	V
V _{CEO}	Collector-Emitter Voltage	-230	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-13	Α
I _B	Base Current	-1.5	Α
P _C	Collector Dissipation (T _C =25°C)	130	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 50 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I_C =-5mA, I_E =0	-230			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =-10mA, R _{BE} =∞	-230			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I_E =-5mA, I_C =0	-5			V
I _{CBO}	Collector Cut-off Current	V _{CB} =-230V, I _E =0			-5.0	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} =-5V, I_{C} =0			-5.0	μΑ
h _{FE1}	* DC Current Gain	V_{CE} =-5V, I_{C} =-1A	55		160	
h _{FE2}	DC Current Gain	V_{CE} =-5V, I_{C} =-7A	35	60		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =-8A, I _B =-0.8A		-0.4	-3.0	V
V _{BE} (on)	Base-Emitter ON Voltage	V_{CE} =-5V, I_{C} =-7A		-1.0	-1.5	V
f _T	Current Gain Bandwidth Product	V_{CE} =-5V, I_{C} =-1A		30		MHz
C _{ob}	Output Capacitance	V _{CB} =-10V, f=1MHz		360	·	pF

^{*} Pulse Test : PW=20us

*h_{FE} Classification

Classification	R	0
h _{FE1}	55 ~ 110	80 ~ 160

Typical Characteristics

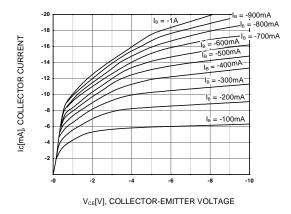


Figure 1. Static Characteristic

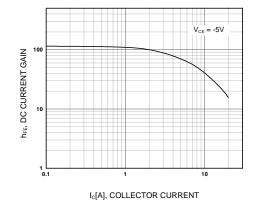


Figure 2. DC current Gain

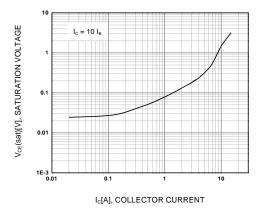


Figure 3. Collector-Emitter Saturation Voltage

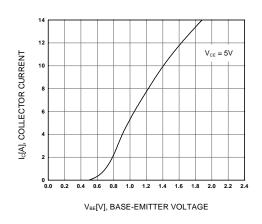


Figure 4. Collector-Emitter Saturation Voltage

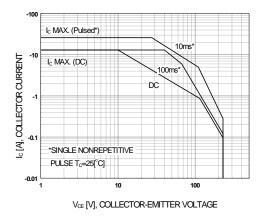


Figure 5. Safe Operating Area

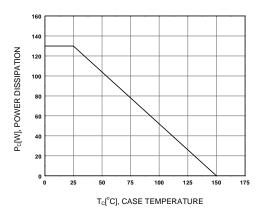
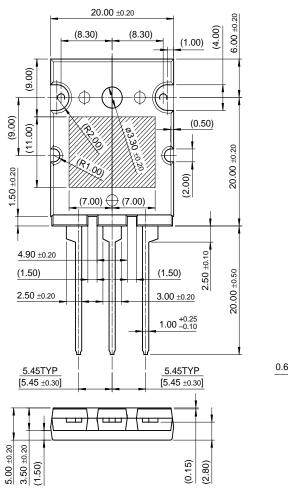


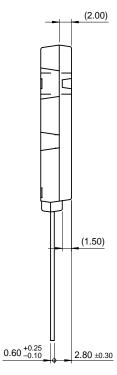
Figure 6. Power Derating

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Package Demensions

TO-264





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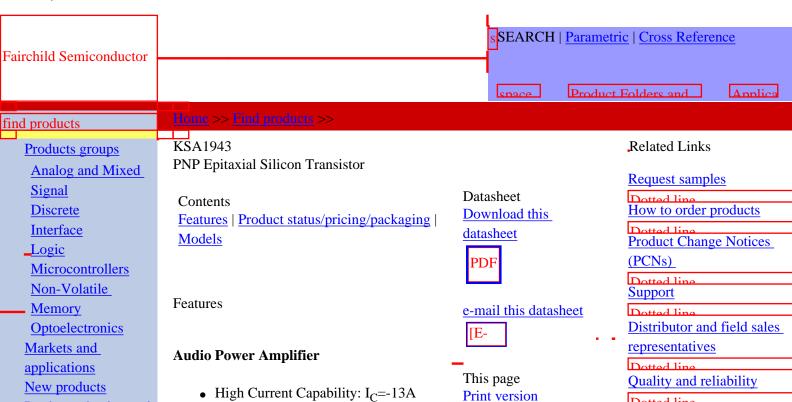
Rev. H4

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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- High Current Capability: I_C=-13A
- High Power Dissipation
- Wide S.O.A.
- Complement to KSC5200

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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSA1943OTU	Full Production	\$1.79	<u>TO-264</u>	3	RAIL
KSA1943RTU	Full Production	\$1.79	<u>TO-264</u>	3	RAIL

^{* 1,000} piece Budgetary Pricing

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Models

Package & leads	Condition	Temperature range Software version		Revision date	
PSPICE					
TO-264-3	Electrical/Thermal	-25°C to 100°C	9	Mar 17, 2000	

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